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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.00233				
I _D (A)	100				
Configuration	Single				
Package	TO-263				

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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G _O	╅╀
N-Channel MOSFET	O _S

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-source voltage		V_{DS}	40	V		
Gate-source voltage		V_{GS}	± 20	V		
Continuous drain current ^a	T _C = 25 °C	1	100			
Continuous drain current "	T _C = 125 °C	I _D	100			
Continuous source current (diode conduction) a	I _S	100	Α			
Pulsed drain current ^b		I _{DM}	280			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	46			
Single pulse avalanche energy	L = 0.1 IIIIA	E _{AS}	105.8	mJ		
Maximum power dissipation ^b	T _C = 25 °C	P_{D}	150	W		
	T _C = 125 °C	L,D	50	VV		
Operating junction and storage temperature range	е	T_J , T_{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient F	PCB mount c	R_{thJA}	40	°C/W	
Junction-to-case (drain)		R_{thJC}	1	G/W	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = 40 V		-	1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	500	μΑ	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	50	-	-	Α	
		V _{GS} = 10 V	I _D = 20 A	-	0.00190	0.00233		
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.00390	Ω	
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.00470		
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 20 A	-	84	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	6445	8000		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{GS} = 0 \text{ V}$ $V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		1931	2700	pF	
Reverse transfer capacitance	C _{rss}			-	179	250		
Total gate charge ^c	Qg	V _{GS} = 10 V V _{DS} = 20 V, I _D = 50 A		-	84	130	nC	
Gate-source charge ^c	Q _{gs}			-	29.5	-		
Gate-drain charge ^c	Q _{gd}			-	19.5	-		
Gate resistance	Rg	f = 1 MHz		0.9	1.83	2.8	Ω	
Turn-on delay time ^c	t _{d(on)}	V_{DD} = 20 V, R_{L} = 0.4 Ω		-	17	30		
Rise time ^c	t _r			-	17	30		
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 50 A$,	V_{GEN} = 10 V, R_g = 1 Ω	-	34	60	ns	
Fall time ^c	t _f	1		-	18	35		
Source-Drain Diode Ratings and Chara	cteristics ^b							
Pulsed current ^a	I _{SM}			-	-	280	Α	
Forward voltage	V _{SD}	I _F = 25 A, V _{GS} = 0 V		-	0.8	1.5	V	
Body diode reverse recovery time	t _{rr}	I _F = 50 A, di/dt = 100 A/μs		-	41	85	ns	
Body diode reverse recovery charge	Q _{rr}			-	28	60	nC	
Reverse recovery fall time	ta			-	24	-		
Reverse recovery rise time	t _b			-	17	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}		-	-1.36	-	Α		

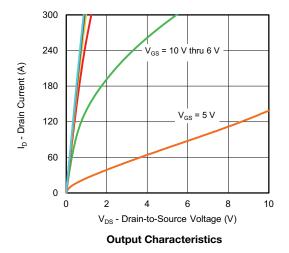
Notes

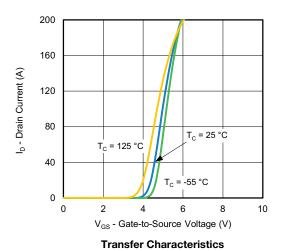
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

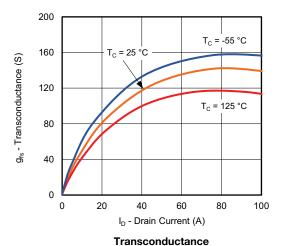
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

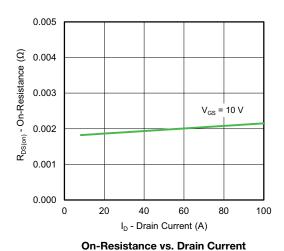


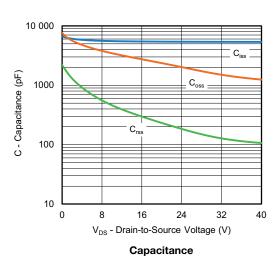
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

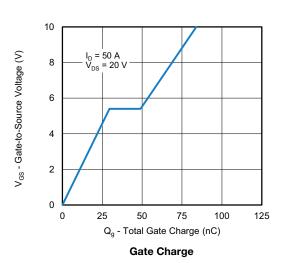






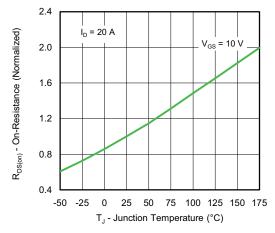




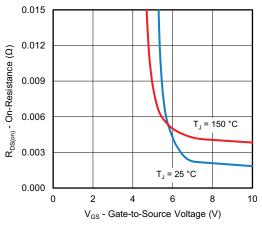




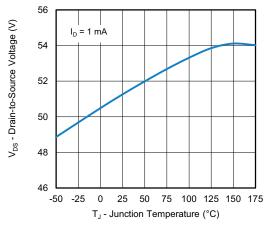
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



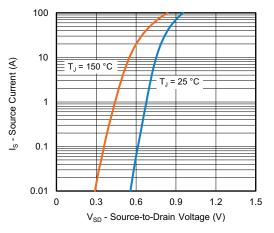
On-Resistance vs. Junction Temperature



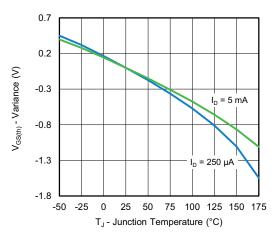
On-Resistance vs. Gate-to-Source Voltage



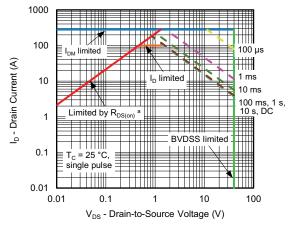
Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage



Threshold Voltage



Safe Operating Area

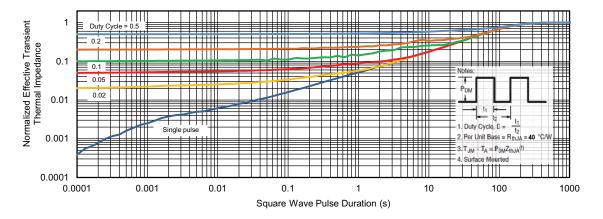
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

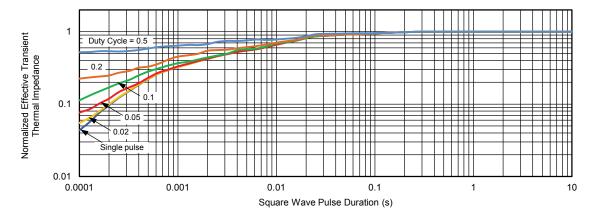
For technical questions, contact: automostech



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

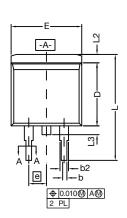
Note

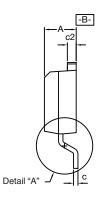
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

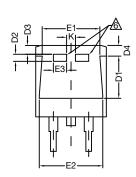
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TO-263 (D²PAK): 3-LEAD

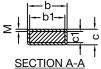








DETAIL A (ROTATED 90°)



_	,	—b - -b	 1			1
2	T			C	_ (<u>-</u>
	SE	^TIC	M	ا م		1

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

		INCHES		MILLIN	METERS	
	DIM.	MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100	BSC	2.54 BSC		
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.010 BSC 0.254 BSC		
М		-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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